

Product Overview

The APTGX200DU120T3AG device is a dual common emitter 1200V, 200A Insulated-Gate Bipolar Transistor (IGBT) 7 power module.

The following figures show the electrical diagram and pinout location of the device.

Figure 1. Electrical Diagram

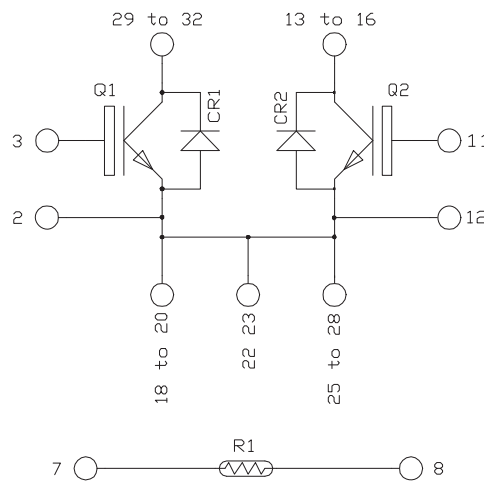
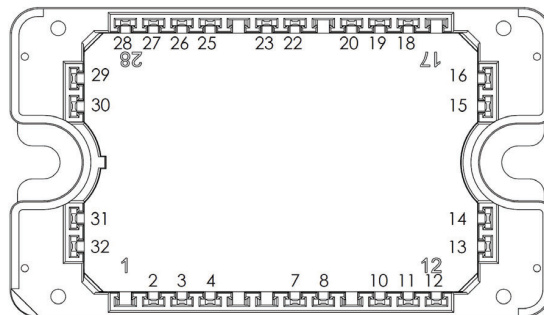


Figure 2. Pinout Location



Notes:

- All multiple inputs and outputs must be shorted together: 13/14/15/16, 18/19/20/22/23/25/26/27/28, and 29/30/31/32.
- All ratings are at $T_J = 25\text{ }^\circ\text{C}$, unless otherwise specified.



These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The APTGX200DU120T3AG device has the following key features:

- IGBT 7
 - Low-voltage drop
 - Low-leakage current
- Very low-stray inductance
- Kelvin emitter for easy drive
- Internal thermistor for temperature monitoring
- AlN substrate for improved thermal performance
- Copper base plate

Benefits

The APTGX200DU120T3AG device has the following benefits:

- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

Potential Applications

The APTGX200DU120T3AG device has the following potential applications:

- AC switches

1. Electrical Specifications

The following sections show the electrical specifications of the APTGX200DU120T3AG device.

1.1 IGBT Characteristics (Per IGBT)

The following table lists the absolute maximum ratings (per IGBT) of the APTGX200DU120T3AG device.

Table 1-1. Absolute Maximum Ratings

Symbol	Parameter	Maximum Ratings	Unit
V_{CES}	Collector-emitter voltage	1200	V
I_C	Continuous collector current	$T_C = 25\text{ }^\circ\text{C}$	350
		$T_C = 110\text{ }^\circ\text{C}$	200
I_{CM}	Pulsed collector current, t_p limited by $T_{J(max)}$	400	A
V_{GE}	Gate-emitter voltage	± 20	V
	Transient gate-emitter voltage	± 25	
P_D	Power dissipation	$T_C = 25\text{ }^\circ\text{C}$	980
			W

The following table lists the electrical characteristics (per IGBT) of the APTGX200DU120T3AG device.

Table 1-2. Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min.	Typ.	Max.	Unit	
I_{CES}	Zero gate voltage collector current	$V_{GE} = 0V$; $V_{CE} = 1200V$	—	—	15	μA	
$V_{CE(sat)}$	Collector-emitter saturation voltage	$V_{GE} = 15V$ $I_C = 200A$	$T_J = 25\text{ }^\circ\text{C}$	—	1.55	1.8	V
			$T_J = 125\text{ }^\circ\text{C}$	—	1.7	—	
			$T_J = 175\text{ }^\circ\text{C}$	—	1.77	—	
$V_{GE(th)}$	Gate threshold voltage	$V_{GE} = V_{CE}$; $I_C = 4.6\text{ mA}$	5.15	5.8	6.45		
I_{GES}	Gate-emitter leakage current	$V_{GE} = 20V$; $V_{CE} = 0V$	—	—	150	nA	

The following table lists the dynamic characteristics (per IGBT) of the APTGX200DU120T3AG device.

Table 1-3. Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min.	Typ.	Max.	Unit	
C_{ies}	Input capacitance	$V_{GE} = 0V$	—	40	—	nF	
C_{oes}	Output capacitance	$V_{CE} = 25V$	—	0.51	—		
C_{res}	Reverse transfer capacitance	$f = 100\text{ kHz}$	—	0.14	—		
Q_G	Gate charge	$V_{GE} = \pm 15V$ $V_{CE} = 600V$ $I_C = 200A$	—	3.3	—	μC	
$T_{d(on)}$	Turn-on delay time	$V_{GE} = \pm 15V$ $V_{BUS} = 600V$ $I_C = 200A$ $R_G = 3\Omega$	$T_J = 25\text{ }^\circ C$	—	172	—	ns
			$T_J = 125\text{ }^\circ C$	—	184	—	
			$T_J = 175\text{ }^\circ C$	—	192	—	
T_r	Rise time		$T_J = 25\text{ }^\circ C$	—	63	—	
			$T_J = 125\text{ }^\circ C$	—	73	—	
			$T_J = 175\text{ }^\circ C$	—	74	—	
$T_{d(off)}$	Turn-off delay time		$T_J = 25\text{ }^\circ C$	—	352	—	
			$T_J = 125\text{ }^\circ C$	—	442	—	
			$T_J = 175\text{ }^\circ C$	—	486	—	
T_f	Fall time	$T_J = 25\text{ }^\circ C$	—	92	—		
		$T_J = 125\text{ }^\circ C$	—	190	—		
		$T_J = 175\text{ }^\circ C$	—	254	—		
E_{on}	Turn-on energy	$V_{GE} = \pm 15V$ $V_{BUS} = 600V$ $I_C = 200A$ $R_G = 3\Omega$ $di/dt = 2300\text{ A}/\mu s$ $dv/dt = 3100\text{ V}/\mu s$	$T_J = 25\text{ }^\circ C$	—	25.5	—	mj
			$T_J = 125\text{ }^\circ C$	—	30.3	—	
			$T_J = 175\text{ }^\circ C$	—	32.8	—	
E_{off}	Turn-off energy		$T_J = 25\text{ }^\circ C$	—	13.6	—	
			$T_J = 125\text{ }^\circ C$	—	20.6	—	
			$T_J = 175\text{ }^\circ C$	—	26.7	—	
R_{Gint}	Internal gate resistance		—	0.75	—	Ω	
I_{sc}	Short circuit data	$V_{GE} \leq 15V$ $V_{BUS} = 800V$ $t_p \leq 8\text{ }\mu s$	$T_J = 150\text{ }^\circ C$	—	640	—	A
		$V_{GE} \leq 15V$ $V_{BUS} = 800V$ $t_p \leq 7\text{ }\mu s$	$T_J = 175\text{ }^\circ C$	—	600	—	
R_{thJC}	Junction-to-case thermal resistance		—	—	0.153	$^\circ C/W$	

1.2 Diode Characteristics (Per Diode)

The following table lists the diode characteristics (per diode) of the APTGX200DU120T3AG device.

Table 1-4. Diode Characteristics

Symbol	Characteristic	Test Conditions		Min.	Typ.	Max.	Unit
V_{RRM}	Peak repetitive reverse voltage			—	—	1200	V
I_{RM}	Reverse leakage current	$V_R = 1200V$		—	—	10	μA
I_{FRM}	Repetitive forward current, t_p limited by $T_{J(max)}$			—	—	400	A
I^2t	I^2t value	$t_p = 10\text{ ms}$ $V_R = 0V$	$T_J = 125\text{ }^\circ C$	—	—	5190	A^2s
			$T_J = 175\text{ }^\circ C$	—	—	4690	
I_F	DC forward current	$T_C = 80\text{ }^\circ C$					
V_F	Diode forward voltage	$I_F = 200A$ $V_{GE} = 0V$	$T_J = 25\text{ }^\circ C$	—	1.75	2	V
			$T_J = 125\text{ }^\circ C$	—	1.6	—	
			$T_J = 175\text{ }^\circ C$	—	1.52	—	
I_{RRM}	Reverse recovery current	$V_{GE} = -15V$ $I_F = 200A$ $V_R = 600V$ $di/dt = 2300\text{ A}/\mu s$	$T_J = 25\text{ }^\circ C$	—	92.5	—	A
			$T_J = 125\text{ }^\circ C$	—	134	—	
			$T_J = 175\text{ }^\circ C$	—	149	—	
Q_{rr}	Reverse recovery charge	$V_{GE} = -15V$ $I_F = 200A$ $V_R = 600V$ $di/dt = 2300\text{ A}/\mu s$	$T_J = 25\text{ }^\circ C$	—	13	—	μC
			$T_J = 125\text{ }^\circ C$	—	27.3	—	
E_{rr}	Reverse recovery energy	$V_{GE} = -15V$ $I_F = 200A$ $V_R = 600V$ $di/dt = 2300\text{ A}/\mu s$	$T_J = 25\text{ }^\circ C$	—	3.6	—	mJ
			$T_J = 125\text{ }^\circ C$	—	8.9	—	
			$T_J = 175\text{ }^\circ C$	—	11.8	—	
R_{thJC}	Junction-to-case thermal resistance			—	—	0.251	$^\circ C/W$

1.3 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the APTGX200DU120T3AG device.

Table 1-5. Thermal and Package Characteristics

Symbol	Characteristic	Min.	Typ.	Max.	Unit		
V _{ISOL}	RMS isolation voltage, any terminal-to-case t = 1 min, 50/60 Hz	4000	—	—	V		
d _{creep}	Creepage distance terminal-to-heatsink	—	12.2	—	mm		
d _{clear}	Clearance distance terminal-to-heatsink	—	11.7	—			
R _{CCE}	Lead resistance terminal-to-chip	T _C = 25 °C, per switch		—	0.8	mΩ	
T _J	Operating junction temperature range	-40	—	175	°C		
T _{STG}	Storage temperature range	-40	—	125			
T _C	Operating case temperature	-40	—	125			
τ _M	Mounting torque	To heatsink	M4	2	—	3	N.m
Wt	Package weight	—	98	—	—	—	g

The following table lists the temperature sensor NTC of the APTGX200DU120T3AG device.

Table 1-6. Temperature Sensor NTC

Symbol	Characteristic	Min.	Typ.	Max.	Unit		
R ₂₅	Resistance at 25 °C	—	50	—	kΩ		
ΔR ₂₅ /R ₂₅	—	—	5	—	%		
B _{25/85}	T ₂₅ = 298.15K	—	3952	—	K		
ΔB/B	—	T _C = 100 °C		—	4	—	%

$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$

T: Thermistor temperature
R_T: Thermistor value at T

Note: For more information, see [APT0406—Using NTC Temperature Sensor Integrated into Power Module](#).

1.4 Typical IGBT Performance Curve

The following figures show the IGBT performance curves of the APTGX200DU120T3AG device.

Figure 1-1. Maximum Thermal Impedance

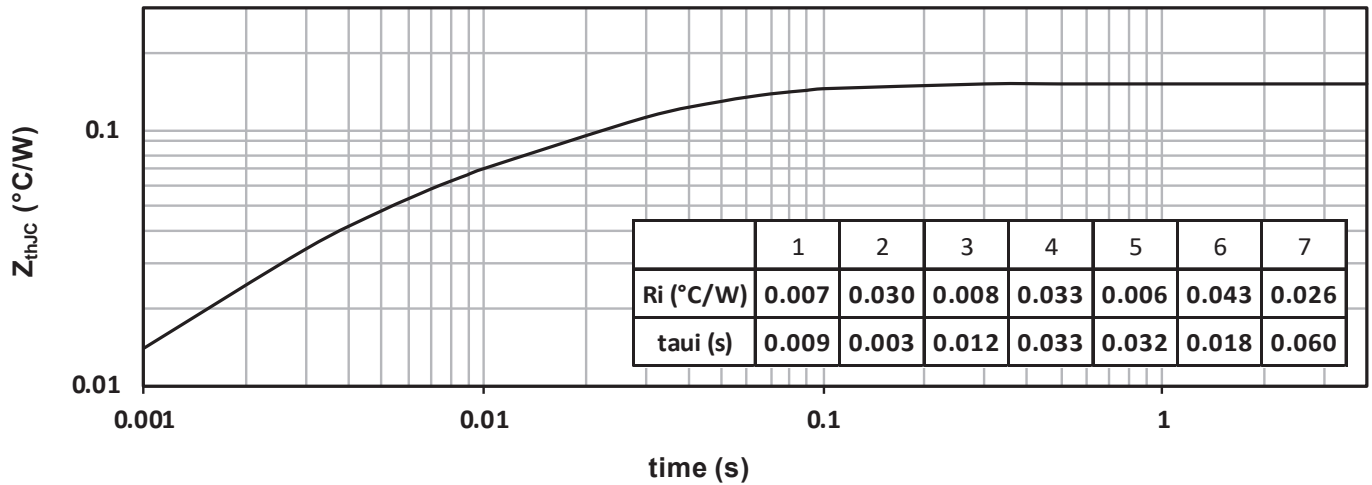


Figure 1-2. Output Characteristics, $V_{GE} = 15V$

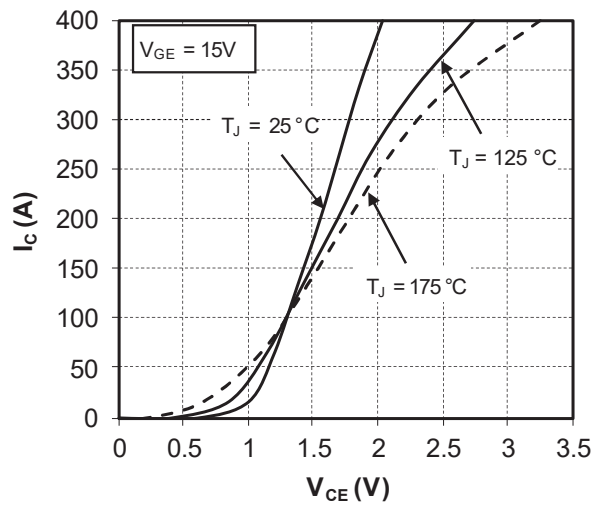


Figure 1-3. Output Characteristics, $T_J = 175\text{ }^\circ\text{C}$

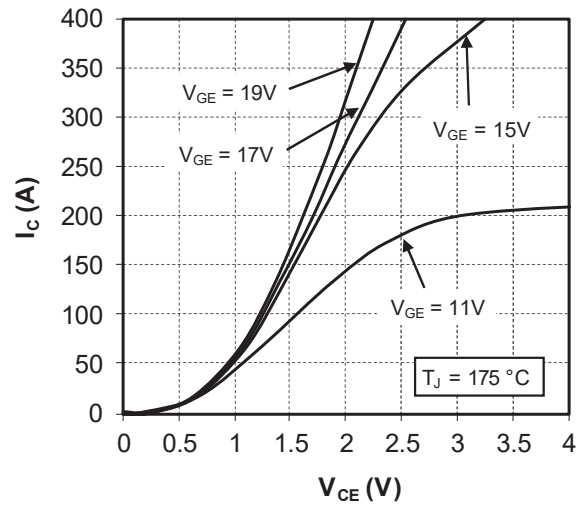


Figure 1-4. Switching Losses vs. Gate Resistance

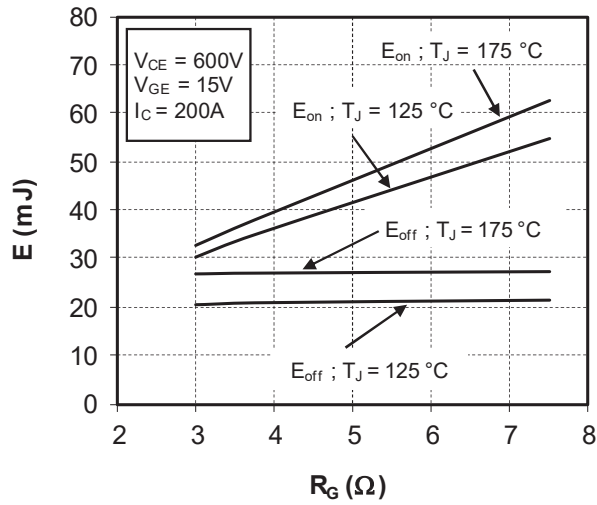


Figure 1-5. Switching Losses vs. Collector Current

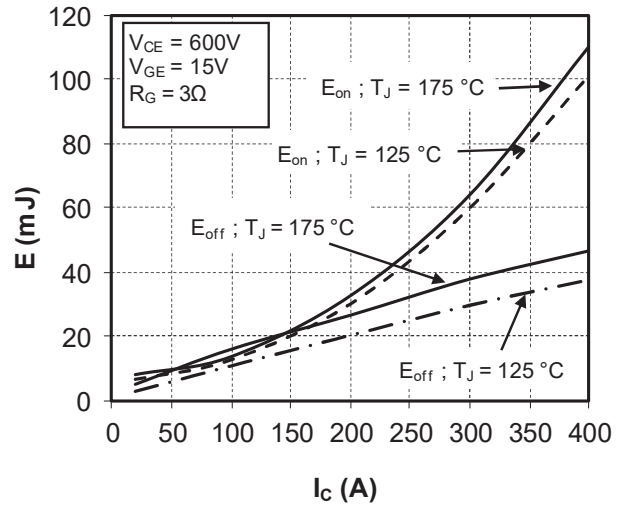


Figure 1-6. Operating Frequency vs. Collector Current

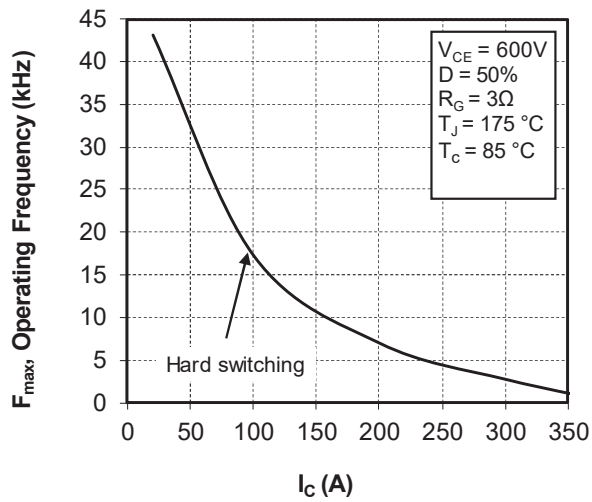


Figure 1-7. Gate Charge Characteristics



Figure 1-8. Transfer Characteristics

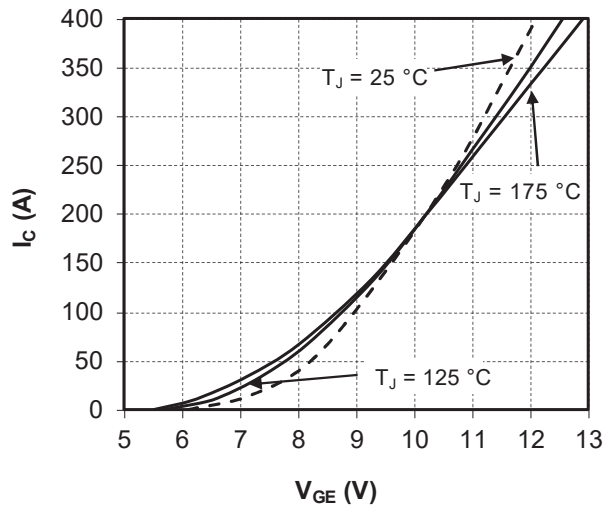


Figure 1-9. Capacity Characteristics

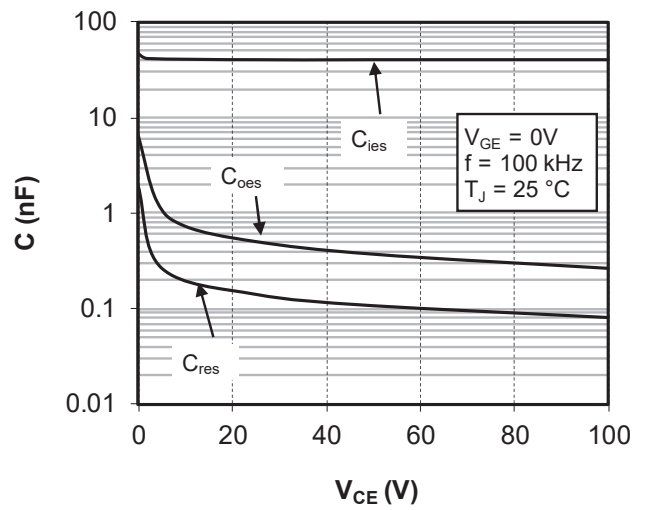
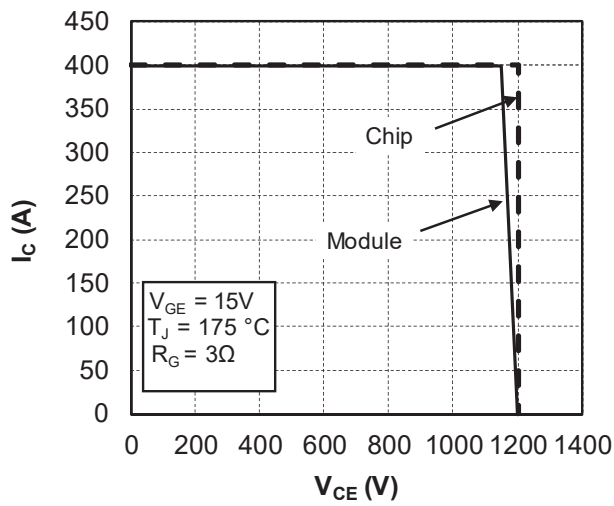


Figure 1-10. Reverse Bias Safe Operating Area



1.5 Typical Diode Performance Curve

The following figures show the diode performance curves of the APTGX200DU120T3AG device.

Figure 1-11. Maximum Thermal Impedance

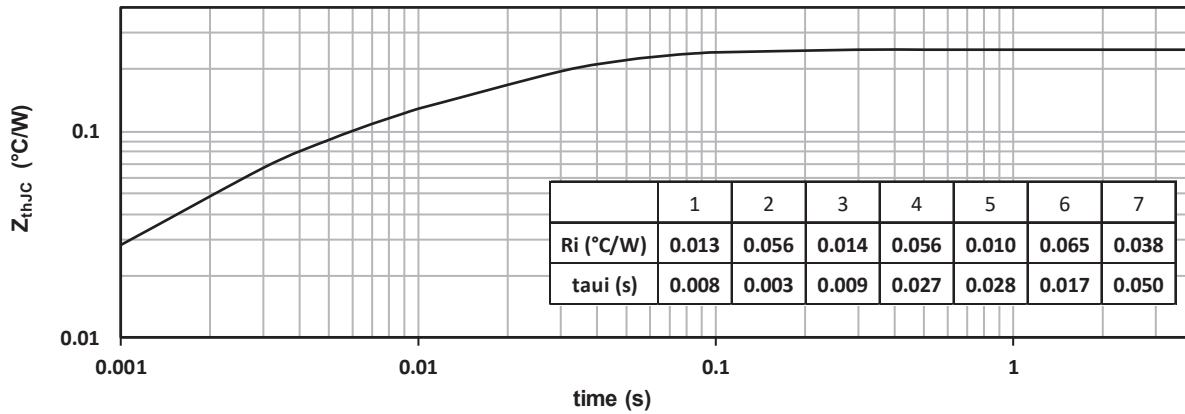


Figure 1-12. Forward Characteristics

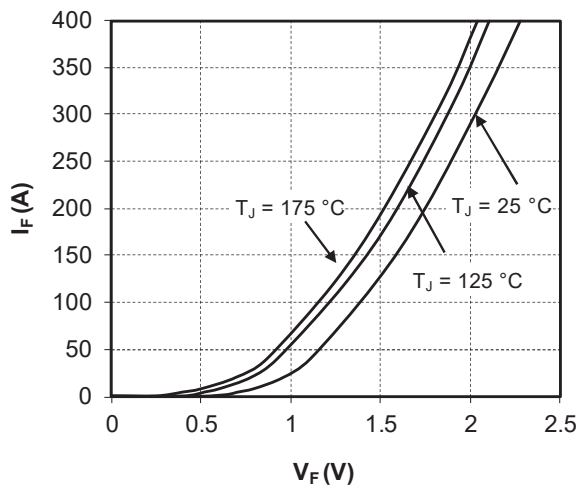


Figure 1-13. Switching Losses vs. Gate Resistance

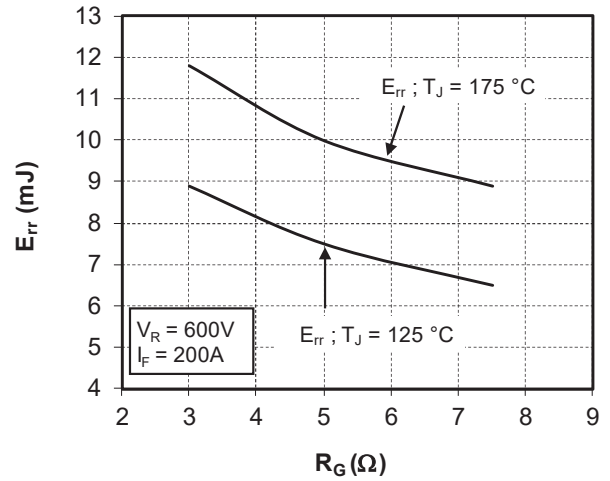
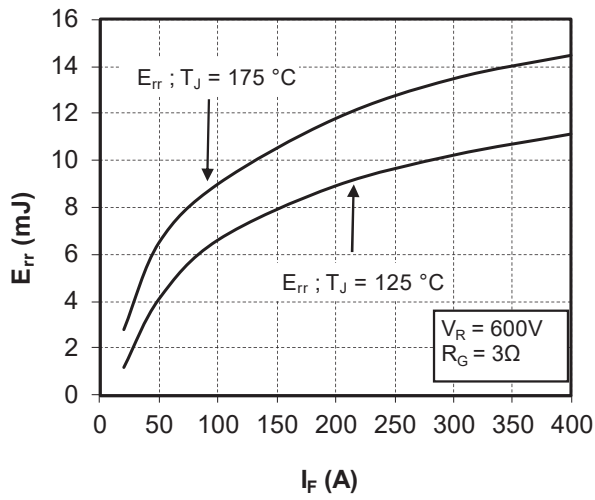


Figure 1-14. Switching Losses vs. Forward Current



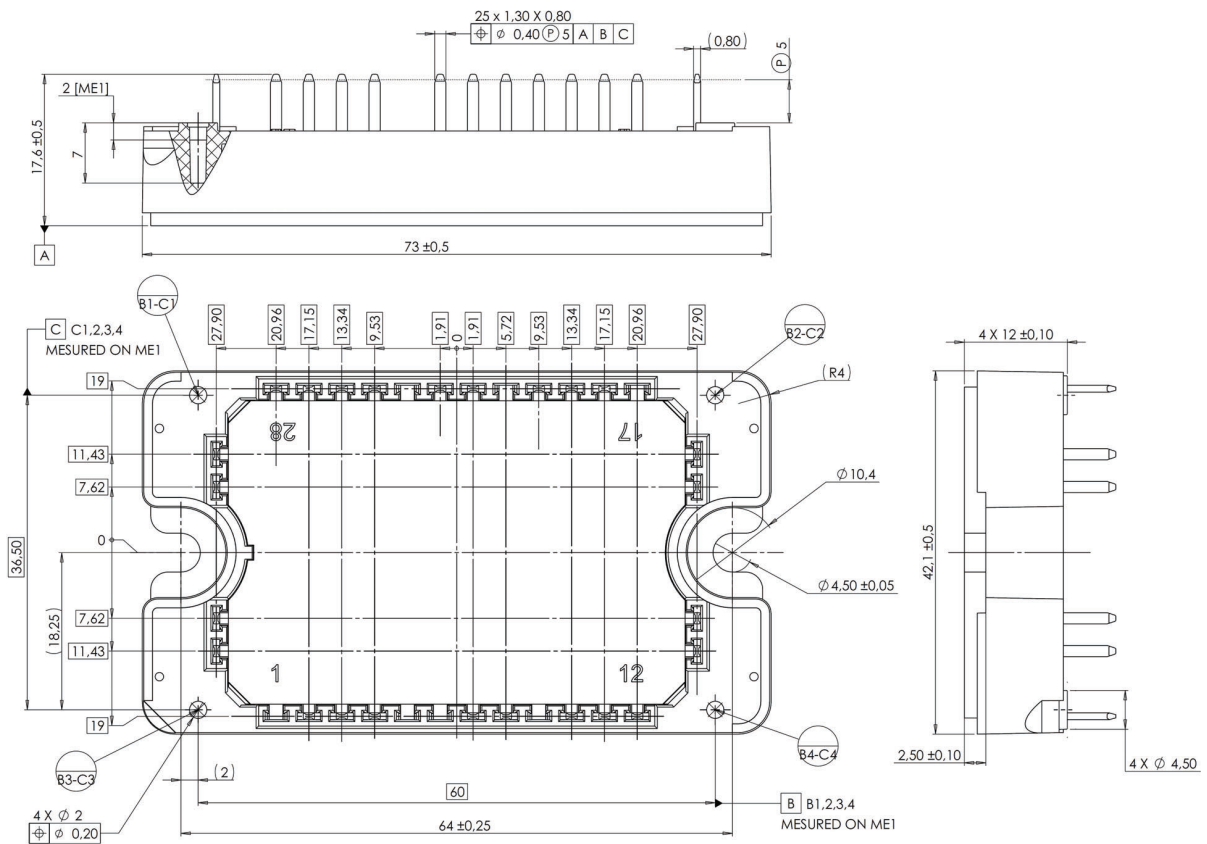
2. Package Specifications

The following section shows the package specification of the APTGX200DU120T3AG device.

2.1 Package Outline

The following figure shows the package outline drawing of the APTGX200DU120T3AG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



Note: For more information, see [AN3500A - Mounting instructions for SP1F and SP3F power modules](#).

3. Revision History

The revision history describes the changes that were implemented in the document. The changes are listed by revision, starting with the most current publication.

Revision	Date	Description
A	09/2024	Initial revision

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